

256 Bit

Commercial
Industrial

X2444
X2444I

16 x 16 Bit

Nonvolatile Static RAM

FEATURES

- **Ideal for use with Single Chip Microcomputers**
 - Static Timing
 - Minimum I/O Interface
 - Serial Port Compatible (COPSTM, 8051)
 - Easily Interfaces to Microcontroller Ports
 - Minimum Support Circuits
- **Software and Hardware Control of Nonvolatile Functions**
 - Maximum Store Protection
- **TTL Compatible**
- **16 x 16 Organization**
- **Low Power Dissipation**
 - Active Current: 15 mA Typical
 - Store Current: 8 mA Typical
 - Standby Current: 6 mA Typical
 - Sleep Current: 5 mA Typical
- **High Reliability**
 - Store Cycles: 100,000
 - Data Retention: 100 Years
- **8 Pin Mini-DIP and 8 Lead SOIC Packages**

DESCRIPTION

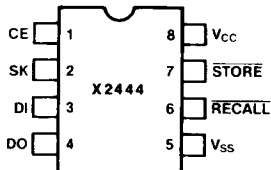
The Xicor X2444 is a serial 256 bit NOVRAM featuring a static RAM configured 16 x 16, overlaid bit for bit with a nonvolatile E²PROM array. The X2444 is fabricated with the same reliable N-channel floating gate MOS technology used in all Xicor 5V nonvolatile memories.

The Xicor NOVRAM design allows data to be transferred between the two memory arrays by means of software commands or external hardware inputs. A store operation (RAM data to E²PROM) is completed in 10 ms or less and a recall operation (E²PROM data to RAM) is completed in 2.5 μ s or less.

Xicor NOVRAMs are designed for unlimited write operations to RAM, either from the host or recalls from E²PROM and a minimum 100,000 store operations. Data retention is specified to be greater than 100 years. Refer to RR-520 and RR-515 for details on Xicor nonvolatile memory endurance and data retention characteristics.

COPSTM is a trademark of National Semiconductor Corp.

PIN CONFIGURATION

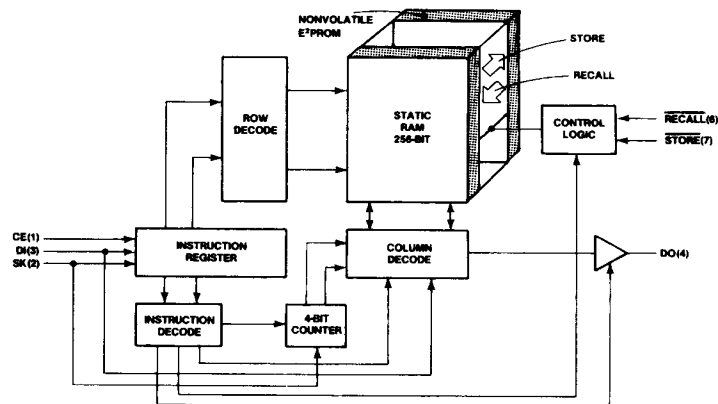


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PIN NAMES

CE	Chip Enable
SK	Serial Clock
DI	Serial Data In
DO	Serial Data Out
RECALL	Recall
STORE	Store
V _{CC}	+ 5V
V _{SS}	Ground

FUNCTIONAL DIAGRAM



0042-2

X2444, X2444I

ABSOLUTE MAXIMUM RATINGS*

Temperature Under Bias	
X2444	–10°C to +85°C
X2444I	–65°C to +135°C
Storage Temperature	–65°C to +150°C
Voltage on any Pin with	
Respect to Ground	–1.0V to +7V
D.C. Output Current	5 mA
Lead Temperature	
(Soldering, 10 Seconds)	300°C

*COMMENT

Stresses above those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. This is a stress rating only and the functional operation of the device at these or any other conditions above those indicated in the operational sections of this specification is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

D.C. OPERATING CHARACTERISTICS

X2444 $T_A = 0^\circ\text{C to } +70^\circ\text{C}$, $V_{CC} = +5\text{V} \pm 5\%$, unless otherwise specified.

X2444I $T_A = -40^\circ\text{C to } +85^\circ\text{C}$, $V_{CC} = +5\text{V} \pm 10\%$, unless otherwise specified.

Symbol	Parameter	X2444 Limits		X2444I Limits		Units	Conditions
		Min.	Max.	Min.	Max.		
I_{CC}	Power Supply Current		15		25	mA	All Inputs = V_{CC} , $I_{I/O} = 0\text{ mA}$
I_{SL}	Sleep Current		7		10	mA	
I_{SB}	Standby Current		10		15	mA	$CE = V_{IL}$
I_{STO}	Store Current		12		15	mA	
I_{LI}	Input Load Current		10		10	μA	$V_{IN} = V_{CC}$
I_{LO}	Output Leakage Current		10		10	μA	$V_{OUT} = V_{CC}$
$V_{IL}^{(2)}$	Input Low Voltage	–1.0	0.8	–1.0	0.8	V	
$V_{IH}^{(2)}$	Input High Voltage	2.0	$V_{CC} + 0.5$	2.0	$V_{CC} + 1.0$	V	
V_{OL}	Output Low Voltage		0.4		0.4	V	$I_{OL} = 2.4\text{ mA}$
V_{OH}	Output High Voltage	2.4		2.4		V	$I_{OH} = -0.8\text{ mA}$

ENDURANCE AND DATA RETENTION

Parameter	Min.	Units	Conditions
Endurance	10,000	Data Changes Per Bit	Xicor Reliability Reports RR-520 and RR-504
Store Cycles	100,000	Store Cycles	Xicor Reliability Reports RR-520 and RR-504
Data Retention	100	Years	Xicor Reliability Report RR-515

CAPACITANCE $T_A = 25^\circ\text{C}$, $f = 1.0\text{ MHz}$, $V_{CC} = 5\text{V}$

Symbol	Test	Max.	Units	Conditions
$C_{I/O}^{(1)}$	Input/Output Capacitance	8	pF	$V_{I/O} = 0\text{V}$
$C_{IN}^{(1)}$	Input Capacitance	6	pF	$V_{IN} = 0\text{V}$

Notes: (1) This parameter is periodically sampled and not 100% tested.

(2) V_{IL} min. and V_{IH} max. are for reference only and are not tested.

X2444, X2444I

2

A.C. CONDITIONS OF TEST

Input Pulse Levels	0V to 3.0V
Input Rise and Fall Times	10 ns
Input and Output Timing Levels	1.5V
Output Load	1 TTL Gate and CL = 100 pF

NONVOLATILE OPERATIONS

Operation	STORE	RECALL	INST	WRITE ENABLE LATCH	Previous RECALL
Hardware Recall	1	0	NOP(3)	X	X
Software Recall	1	1	RCL	X	X
Hardware Store	0	1	NOP(3)	SET	True
Software Store	1	1	STO	SET	True

A.C. CHARACTERISTICS

X2444 TA = 0°C to +70°C, VCC = +5V ± 5%, unless otherwise specified.
X2444I TA = -40°C to +85°C, VCC = +5V ± 10%, unless otherwise specified.

Read and Write Cycle Limits

Symbol	Parameter	Min.	Max.	Units
Fsk	SK Frequency		1.0	MHz
tSKH	SK Positive Pulse Width	0.4		μs
tSKL	SK Negative Pulse Width	0.4		μs
tDS	Data Setup Time	0.4		μs
tDH	Data Hold Time	0.08		μs
tPD1	SK  to Data 0 Valid		375	ns
tPD	SK  to Data Valid		375	ns
tZ	Chip Enable to Output High Z		1.0	μs
tCES	Chip Enable Setup	0.8		μs
tCEH	Chip Enable Hold	0.4		μs
tCDS	Chip Deselect	0.8		μs

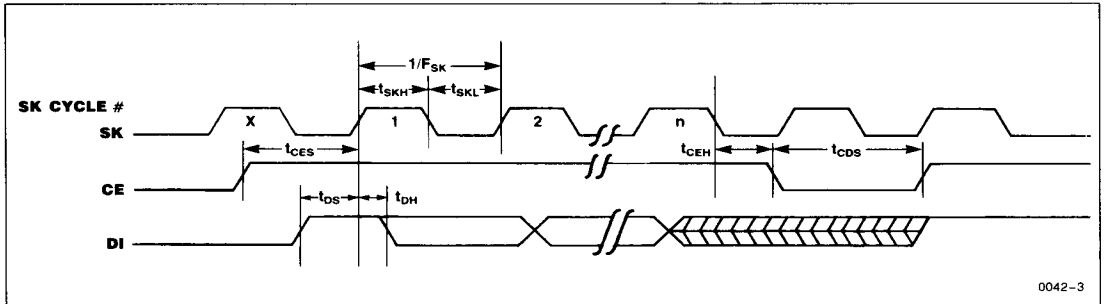
Power-Up Timing(4)

Symbol	Parameter	Typical(5)	Units
tPUR	Power-Up to Read Operation	2.5	μs
tPUW	Power-Up to Write Operation	2.5	μs

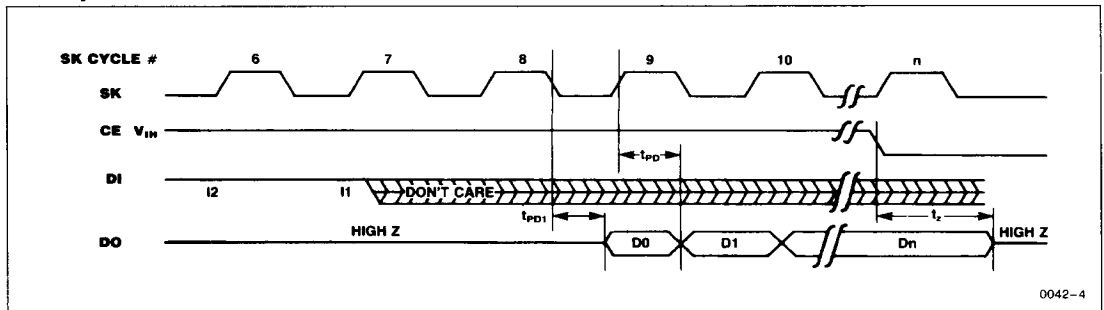
Notes: (3) NOP designates when the X2444 is not currently executing an instruction.
(4) tPUR and tPUW are the delays required from the time VCC is stable until the specified operation can be initiated. These parameters are periodically sampled and not 100% tested.
(5) Typical values are for TA = 25°C and VCC = 5V.

X2444, X2444I

Write Cycle



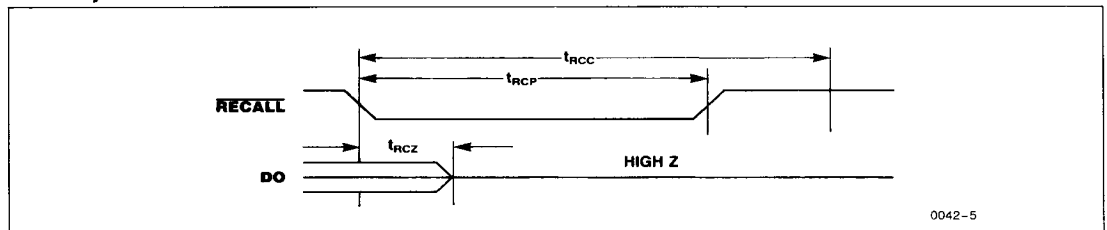
Read Cycle



Array Recall Cycle Limits

Symbol	Parameter	Min.	Max.	Units
t_{RCC}	Recall Cycle Time	2.5		μs
t_{RCP}	Recall Pulse Width ⁽⁶⁾	1.0		μs
t_{RCZ}	Recall to Output High Z		0.5	μs

Recall Cycle



Note: (6) Recall rise time must be $< 10 \mu s$.

X2444, X2444I

Store Cycle Limits

Symbol	Parameter	Min.	Typ.(7)	Max.	Units
t _{ST}	Store Time		5	10	ms
t _{STP}	Store Pulse Width	0.2			μs
t _{STZ}	Store To Output High Z			1.0	μs
V _{CC}	Store Inhibit		3		V

2

Hardware Store

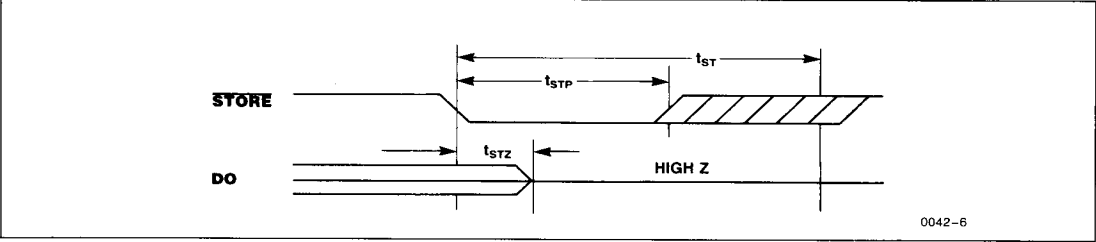
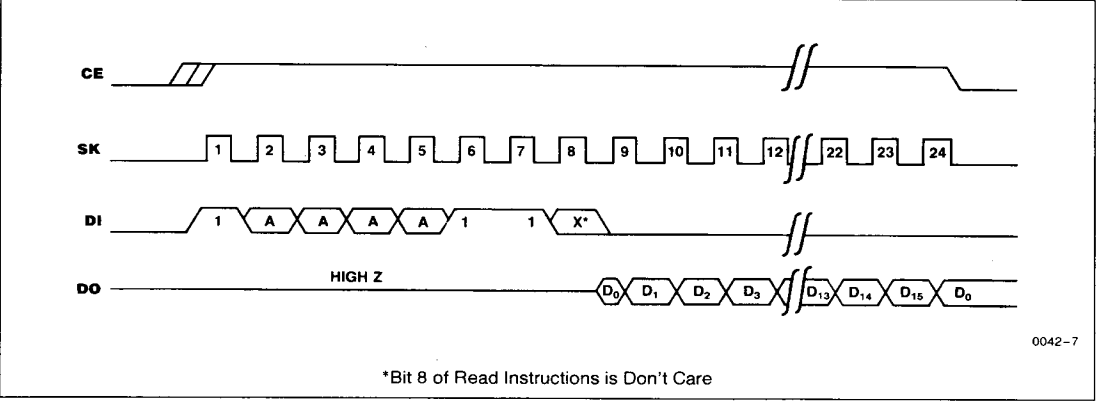


Figure 1: RAM Read



Note: (7) Typical values are for T_A = 25°C and nominal supply voltage.

X2444, X2444I

Figure 2: RAM Write

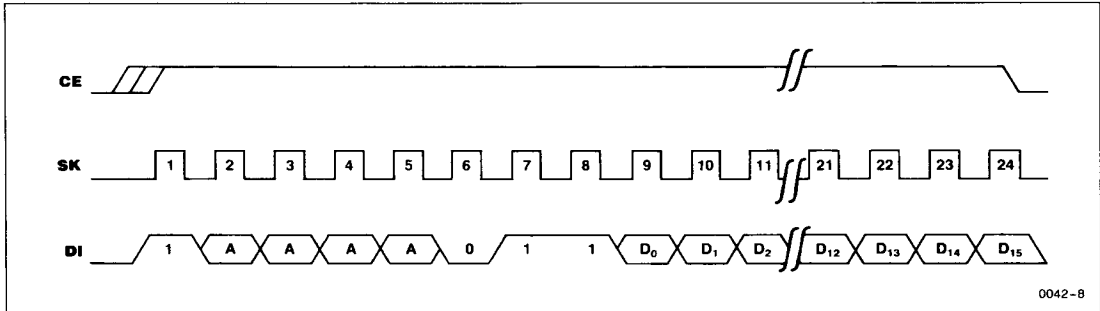


Figure 3: Non-Data Operations

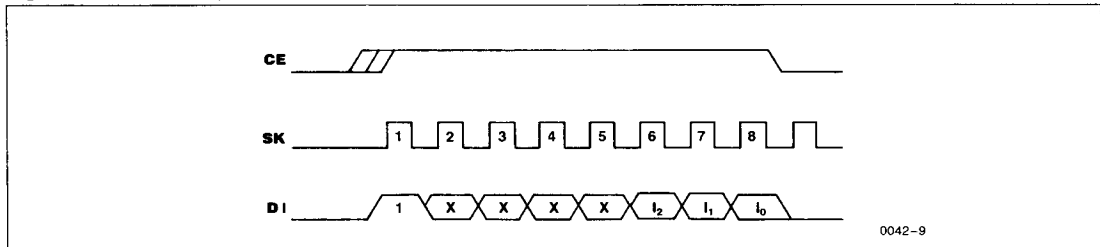


TABLE 1: INSTRUCTION SET

Instruction	Format, $I_2 I_1 I_0$	Operation
WRDS (Figure 3)	1XXXX000	Reset Write Enable Latch (Disables writes and stores)
STO (Figure 3)	1XXXX001	Store RAM Data in E ² PROM
SLEEP (Figure 3)	1XXXX010	Enter SLEEP Mode
WRITE (Figure 2)	1AAAA011	Write Data into RAM Address AAAA
WREN (Figure 3)	1XXXX100	Set Write Enable Latch (Enables writes and stores)
RCL (Figure 3)	1XXXX101	Recall E ² PROM Data into RAM
READ (Figure 1)	1AAAA11X	Read Data from RAM Address AAAA

X = Don't Care
A = Address Bit

X2444, X2444I

PIN DESCRIPTIONS

Chip Enable (CE)

The Chip Enable input must be HIGH to enable read/write operations. CE must remain HIGH following a Read or Write command until the data transfer is complete. CE LOW places the X2444 in the standby power mode and resets the instruction register. Therefore, CE must be brought LOW after the completion of an operation in order to reset the instruction register in preparation for the next command.

Serial Clock (SK)

The Serial Clock input is used to clock all data into and out of the device.

Data In (DI)

Data In is the serial data input.

Data Out (DO)

Data Out is the serial data output. It is in the high impedance state except during data output cycles in response to a READ instruction.

STORE

STORE LOW will initiate an internal transfer of data from RAM to E²PROM.

RECALL

RECALL LOW will initiate an internal transfer of data from E²PROM to RAM.

DEVICE OPERATION

The X2444 contains an 8-bit instruction register. It is accessed via the DI input, with data being clocked in on the rising edge of SK. CE must be HIGH during the entire data transfer operation.

Table 1 contains a list of the instructions and their operation codes. The most significant bit (MSB) of all instructions is a one, bits 6 through 3 are either RAM address (A) or don't care (X) and bits 2 through 0 are the operation codes. The X2444 requires the instruction to be shifted in with the MSB first.

After CE is HIGH, the X2444 will not begin to interpret the data stream until a one has been shifted in on DI. Therefore, CE may be brought HIGH with SK running and DI LOW. DI must then go HIGH to indicate the start condition of an instruction before the X2444 will begin any action.

In addition, the SK clock is totally static. The user can completely stop the clock and data shifting will be stopped. Restarting the clock will resume shifting of data.

WRDS and WREN

Internally the X2444 contains a "write enable" latch. This latch must be set for either writes to the RAM or store operations to the E²PROM. The WREN instruction sets the latch and the WRDS instruction resets the latch, disabling *both* RAM writes and E²PROM stores. The write enable latch is automatically reset on power-up.

SLEEP

The SLEEP instruction removes power from the RAM, placing the X2444 in a very low power quiescent state. Data in the RAM is lost once a SLEEP instruction is issued; however, data from the last store operation is retained in the E²PROM. The sleep mode can be exited by either a software or hardware recall operation.

RCL and RECALL

Either the RCL instruction or a LOW on the RECALL input will initiate a transfer of E²PROM data into RAM. A recall operation must be performed after a power-up before any store or RAM write operation can be enabled. This recall operation and the recall recovery from the sleep mode guarantees a known state of data in RAM. Both recall operations set an internal "previous recall" latch which must be set to enable any write or store operations.

STO and STORE

Either the STO instruction or a LOW on the STORE input will initiate the transfer of data from RAM to E²PROM. In order to safeguard against unwanted store operations, the following conditions must be true:

1. STO instruction issued or STORE input is LOW;
2. The internal write enable latch must be set (WREN instruction issued);
3. The "previous recall" latch must be set.

Once the store cycle is initiated, all other device functions are inhibited. Upon completion of the store cycle, the write enable latch is reset.

X2444, X2444I

WRITE

The write instruction contains the 4 bit address of the word to be written. The write instruction is immediately followed by the 16-bit word to be written. CE must remain HIGH during the entire operation. If CE is brought LOW prematurely (after the instruction but before 16 bits of data are transferred), the instruction register will be reset and the data that was shifted in will be written to RAM. If CE is kept HIGH for more than 24 SK clock cycles (8-bit instruction plus 16-bit data) the data already shifted in will be overwritten.

READ

The read instruction contains the 4 bit address of the word to be accessed. Unlike the other six instructions, I_0 is a "don't care" for the read instruction. This provides two advantages. In a design that ties both DI and DO together, the absence of an eighth bit in the instruction allows the host time to convert an I/O line from an output to an input. Secondly, it allows for valid data output during the ninth SK clock cycle.

DO, the first bit output during a read operation, is truncated. That is, it is internally clocked by the falling edge of the eighth SK clock; whereas, all succeeding bits are clocked by the rising edge of SK (refer to Read Cycle Diagram).

WRITE PROTECTION

The X2444 provides three hardware and software write protection mechanisms to prevent inadvertent stores of unknown data.

Power-Down Condition

(when "write enable" latch and "previous recall" latch are not in the reset state):

- Write Inhibit—Holding either $\overline{\text{RECALL}}$ LOW, CE LOW or $\overline{\text{STORE}}$ HIGH during power-down will prevent an inadvertent store.

Power-Up Condition

- Write Enable Latch—Upon power-up the "write enable" latch is in the reset state, disabling any store operation.

Unknown Data Store

- Previous Recall Latch—The "previous recall" latch must be set after power-up and after exiting the sleep mode. It may be set only by performing a recall operation, which assures that data in all RAM locations is valid.

LOW POWER MODES

The X2444 provides two power conservation modes. When CE is LOW, non-critical internal devices are powered-down, placing the device in the standby power mode. Entering the sleep mode removes power from the entire RAM array, placing the device in a very low power quiescent state (sleep mode).

Part Number	Store Cycles	Data Changes Per Bit
X2444	100,000	10,000
X2444I	100,000	10,000

SYSTEM CONSIDERATIONS

Power-Down Data Protection

Because the X2444 is a 5V only nonvolatile memory device it may be susceptible to inadvertent writes to the E²PROM array during power-down cycles. Power-up cycles are not a problem because the previous recall latch and write enable latch are reset, preventing any possible corruption of E²PROM data.

If the $\overline{\text{STORE}}$ and $\overline{\text{RECALL}}$ pins are tied to V_{CC} through a pullup resistor and only software store operations are performed to initiate stores, there is little likelihood of an inadvertent store. However, if these two lines are under microprocessor control, positive action should be employed to negate the possibility of these control lines bouncing and generating an unwanted

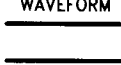
store. The safest method is to issue the WRDS command after a write sequence and also following store operations. Note: an internal store may take up to 10 ms; therefore, the host microprocessor should delay 10 ms after initiating the store prior to issuing the WRDS command.

Power-On Recall

The X2444 performs a power-on recall that transfers the E²PROM contents to the RAM array. Although the data may be read from the RAM array, this recall does not set the previous recall latch. During this power-on recall operation, all commands are ignored. Therefore, the host should delay any operation with the X2444 a minimum 2.5 μs (t_{RCC}) after V_{CC} is stable.

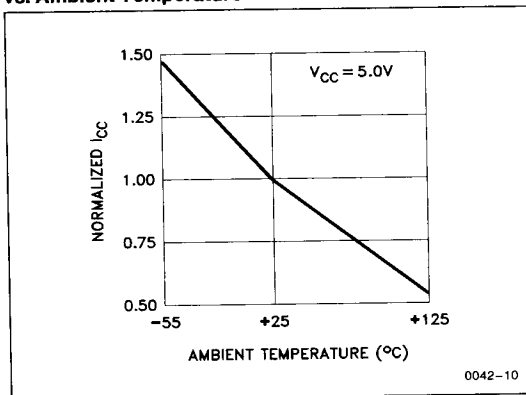
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SYMBOL TABLE

WAVEFORM	INPUTS	OUTPUTS
	Must be steady	Will be steady
	May change from Low to High	Will change from Low to High
	May change from High to Low	Will change from High to Low
	Don't Care : Changes Allowed	Changing : State Not Known
	N/A	Center Line is High Impedance

X2444, X2444I

**Normalized Active Supply Current
vs. Ambient Temperature**



**Normalized Standby Supply Current
vs. Ambient Temperature**

